



Multicrystalline I-Cells

Dimension	156.75mm x 156.75mm ± 0.25mm
Thickness(Si)	180µm ± 20µm, 200µm ± 20µm
Front	Blue silicon nitride anti-reflection coatings
	0.7±0.1mm silver busbars
BI	Full-surface aluminum back-surface field
Back	1.7±0.1mm (silver / aluminum) discontinuous soldering pads



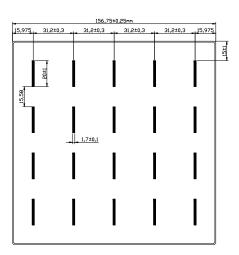
Features

- High conversion efficiencies resulting in superior power output performance
- Outstanding power output even in low light or high temperature conditions
- Optimized design for ease of soldering and lamination
- Long-term stability, reliability and performance
- > Low breakage rate
- > Uniform Color
- > Diamond Wire Wafer

156,75±0,25mm 15,975 31,2±0,15 31,2±0,15 31,2±0,15 15,975 15,975 31,2±0,15 31,2±0,15 31,2±0,15 15,975 15,975 31,2±0,15 31,2±0,15 31,2±0,15 15,975 15,975 31,2±0,15 31,2±0,15 31,2±0,15 15,975 15,975 31,2±0,15 31,2±0,15 31,2±0,15 15,975 15,975 31,2±0,15 31,2±0,15 31,2±0,15 15,975 15,975 31,2±0,15 31,2±0,15 31,2±0,15 15,975 15,975 31,2±0,15 31,2±0,15 31,2±0,15 15,975 15,975 31,2±0,15 31,2±0,15 31,2±0,15 31,2±0,15 15,975 15,975 31,2±0,15 31,2±0,15 31,2±0,15 31,2±0,15 15,975 15,975 31,2±0,15 31,2±0,15 31,2±0,15 31,2±0,15 15,975 15,975 31,2±0,15 31,2±0,15 31,2±0,15 31,2±0,15 15,975 15,975 31,2±0,15 31,2±0,15 31,2±0,15 15,975 15,975 31,2±0,15 31,2±0,15 31,2±0,15 15,975 15,975 31,2±0,15 31,2±0,15 31,2±0,15 15,975 15,975 31,2±0,15 31,2±0,15 31,2±0,15 15,975 15,975 31,2±0,15 31,2±0,15 31,2±0,15 15,975 15,975 31,2±0,15 31,2±0,15 31,2±0,15 15,975 15,975 31,2±0,15 31,2±0,15 15,2±0,15 15,2±0,15 15,2±0,15 15,2±0,15 15,2±0,15 15,2±0,15 15,2±0,15 15,2±0,15 15,2±

Production and Quality Control

- > Precision cell efficiency sorting procedures
- > Stringent criteria for color uniformity and appearance
- > Reverse current and shunt resistance screening
- > ISO9001, ISO14001 and OHSAS 18001 certificated
- > Calibrated against Fraunhofer ISE



^{*} See the reverse side for more detail





Electrical Performance

Efficiency Code		190	188	187	186
Efficiency	Eff(%)	19.00	18.80	18.70	18.60
Power	Ppm(W)	4.67	4.62	4.59	4.57
Max. Power Current	Ipm(A)	8.54	8.49	8.47	8.45
Short Circuit Curren	t Isc(A)	9.02	8.97	8.95	8.92
Max. Power Voltage	Vpm(V)	0.547	0.544	0.543	0.541
Open Circuit Voltage	Voc(V)	0.643	0.640	0.639	0.638
Efficiency Code		185	184	182	180
Efficiency	Eff(%)	18.50	18.40	18.20	18.00
Efficiency Power	Eff(%)	18.50 4.55	18.40 4.52	18.20 4.47	18.00
	Ppm(W)				
Power	Ppm(W) Ipm(A)	4.55	4.52	4.47	4.42
Power Max. Power Current	Ppm(W) Ipm(A) t Isc(A)	4.55 8.42	4.52 8.40	4.47 8.36	4.42 8.31

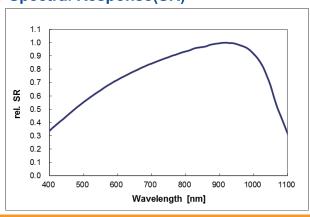
Standard test conditions: AM1.5, 1000W/m², 25°C. Average accuracy of all tested figures is ±1.5% rel.

○ Temperature Coefficients

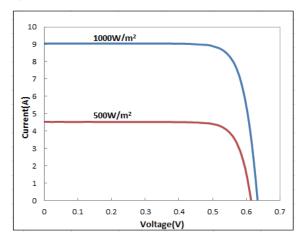
Current Temperature Coefficient	α(Isc)	0.04%/°C
Voltage Temperature Coefficient	β(Voc)	-0.31%/°C
Power Temperature Coefficient	γ (Pmax)	-0.39%/°C

Standard test conditions: AM1.5, 1000W/m², 25°C.

Spectral Response(SR)



○ IV Curve



Specifications subject to change without prior notice. MOTECH reserves the rights of final interpretation and revision of this datasheet.

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